

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

1-16. (Canceled)

17. (Currently Amended) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region over the substrate;
forming a third electrode over the substrate for forming a protective capacitor, wherein
the third electrode surrounds the active matrix circuit region and the driver circuit region, and
wherein the first through the third electrodes are electrically connected with each other; and
electrically separating the third electrode from the first and the second electrodes.

18. (Previously Presented) A method for manufacturing a display device according to
claim 17, wherein the first through the third electrodes comprise aluminum.

19. (Canceled)

20. (Previously Presented) A method for manufacturing a display device according to
claim 17, wherein the display device is a liquid crystal display device.

21. (Previously Presented) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region over the substrate;

forming a third electrode over the substrate, wherein the third electrode surrounds the active matrix circuit region and the driver circuit region, wherein the first through the third electrodes are on a same layer, and wherein the first through the third electrodes are electrically connected with each other; and

electrically separating the third electrode from the first and the second electrodes.

22. (Previously Presented) A method for manufacturing a display device according to claim 21, wherein the first through the third electrodes comprise aluminum.

23. (Previously Presented) A method for manufacturing a display device according to claim 21, wherein the third electrode is an electrode for forming a protective capacitor.

24. (Previously Presented) A method for manufacturing a display device according to claim 21, wherein the display device is a liquid crystal display device.

25. (Previously Presented) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region over the substrate;
forming a third electrode over the substrate, wherein the third electrode surrounds the active matrix circuit region and the driver circuit region, wherein the third electrode has a larger width than that of the first and the second electrodes, and wherein the first through the third electrodes are electrically connected with each other; and
electrically separating the third electrode from the first and the second electrodes.

26. (Previously Presented) A method for manufacturing a display device according to claim 25, wherein the first through the third electrodes comprise aluminum.

27. (Previously Presented) A method for manufacturing a display device according to claim 25, wherein the third electrode is an electrode for forming a protective capacitor.

28. (Previously Presented) A method for manufacturing a display device according to claim 25, wherein the display device is a liquid crystal display device.

29. (Previously Presented) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region over the substrate;
forming a third electrode over the substrate, wherein the third electrode is located outside the active matrix circuit region and the driver circuit region, wherein the third electrode has a larger width than that of the first and the second electrodes, and wherein the first through the third electrodes are electrically connected with each other; and
electrically separating the third electrode from the first and the second electrodes.

30. (Previously Presented) A method for manufacturing a display device according to claim 29, wherein the display device is a liquid crystal display device.

31. (Previously Presented) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region over the substrate;
forming a third electrode over the substrate for forming a protective capacitor, wherein the third electrode is located outside the active matrix circuit region and the driver circuit region, wherein the third electrode has a larger width than that of the first and the second electrodes, and wherein the first through the third electrodes are electrically connected with each other; and
electrically separating the third electrode from the first and the second electrodes.

32. (Previously Presented) A method for manufacturing a display device according to claim 31, wherein the display device is a liquid crystal display device.

33. (Previously Presented) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region over the substrate;
forming a third electrode over the substrate, wherein the third electrode is located outside the active matrix circuit region and the driver circuit region, wherein the third electrode has a larger width than that of the first and the second electrodes, and wherein the first through the third electrodes comprise aluminum and are electrically connected with each other; and
electrically separating the third electrode from the first and the second electrodes.

34. (Previously Presented) A method for manufacturing a display device according to claim 33, wherein the display device is a liquid crystal display device.

35. (Previously Presented) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region over the substrate;
forming a third electrode over the substrate for forming a protective capacitor, wherein the third electrode is located outside the active matrix circuit region and the driver circuit region, wherein the third electrode has a larger width than that of the first and the second electrodes, and wherein the first through the third electrodes comprise aluminum and are electrically connected with each other; and
electrically separating the third electrode from the first and the second electrodes.

36. (Previously Presented) A method for manufacturing a display device according to claim 35, wherein the display device is a liquid crystal display device.

37. (New) A method for manufacturing a display device comprising:
forming at least two first conductive layers in an active matrix circuit region over a substrate;
forming a second conductive layer over the substrate, wherein the second conductive layer is electrically connected to the two first conductive layers and is located between the active matrix circuit region and an edge of the substrate,
electrically separating the second conductive layer from the two first conductive layers,
and
wherein the second conductive layer forms a protective capacitor using the second conductive layer as an electrode.

38. (New) A method for manufacturing a display device according to claim 37, wherein the two first conductive layers are a gate line and a source line.

39. (New) A method for manufacturing a display device according to claim 37, wherein the second conductive layer surrounds the active matrix circuit region.

40. (New) A method for manufacturing a display device according to claim 37, wherein the display device further comprising a third conductive layer in a driver circuit region over the substrate.

41. (New) A method for manufacturing a display device according to claim 37, wherein the protective capacitor comprises another electrode which comprises a semiconductor layer.

42. (New) A method for manufacturing a display device according to claim 37, wherein the first and the second conductive layers comprise aluminum.